# **GN04054N**

## GaAs N-Channel IC

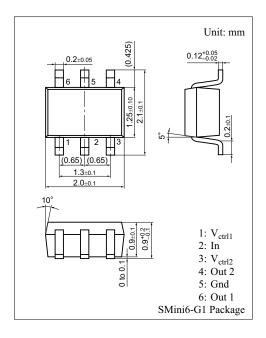
High handling power SPDT SW-IC for UMTS mobile phone

#### ■ Features

- Handling power: 1 W
- Low insertion LOSS: 0.28 dB (typ.)
- Ultra small package (1.25 mm  $\times$  2.0 mm  $\times$  0.9 mm)

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Power dissipation	$P_{\mathrm{D}}$	150	mW	
Control voltage	$V_{\text{ctrl}(H)}$ - $V_{\text{ctrl}(L)}$	+5	V	
Maximum control voltage	V <sub>ctrl(H)max</sub>	+5	V	
Minimum control voltage	V <sub>ctrl(L)min</sub>	-1	V	
Maximum input power	$P_{IN}$	35	dBm	
Operating ambient temperature	T <sub>opr</sub>	-30 to +90	°C	
Storage temperature	T <sub>stg</sub>	-40 to +120	°C	



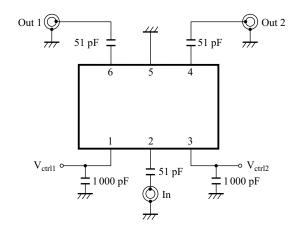
## $\blacksquare \ \, \text{Electrical Characteristics} \ \, V_{ctrl(L)} = 0 \, V, \, V_{ctrl(H)} = 3.0 \, V, \, f = 1\,920 \, \, \text{MHz} \, \, \text{to} \, \, 2\,170 \, \, \text{MHz}, \, T_a = 25^{\circ} \text{C} \pm 3^{\circ} \text{C} \, \text{C}$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Insertion loss	LOSS	In - Out 1, 2 ( $P_{IN} = 26.0 \text{ dBm}$ )		0.28	0.45	dB
Isolation	ISO	In - Out 1, 2 (P <sub>IN</sub> = 26.0 dBm) (Correspond of In - Out 2, 1 ON)	21	27		dB
Voltage standing wave ratio *	VSWR	In - Out 1, 2		1.10	1.30	_
Input 0.1 dB compression	P <sub>IN(0.1 dB)</sub>			31	30	dBm
A discourt abound locked a navier commercial *	ACPR1 In - Out 1, 2 ( $P_{IN}$ = 26.0 dBm) HPSK modulation, ±5 MHz offset from the carrier, 3.84 MHz Bandwidth, Load VSWR $\leq$ 3.0 , All phase		-59	-43		
Adjacent channel leakage power suppression *	ACPR2	In - Out 1, 2 ( $P_{IN}$ = 26.0 dBm) HPSK modulation, ±10 MHz offset from the carrier, 3.84 MHz Bandwidth, Load VSWR $\leq$ 3.0 , All phase		-63	-55	dBc
2nd harmonics *	$2f_{O}$	In - Out 1, 2 (P <sub>IN</sub> = 26.0 dBm)		-74	-65	dBc
3rd harmonics *	$3f_{O}$	Non-modulation signal		-80	-70	dBc
IMD3 *	IMD3	$f_{TX} = 1950 \text{ MHz}, P_{IN} = 20 \text{ dBm}$ $f_{jammer} = 1760 \text{ MHz}, P_{IN} = 20 \text{ dBm}$ 2 tone CW, $f_{RX} = 2140 \text{ MHz}$		-108.8	-105	dBm/ 1.2 MHz
Control current	I <sub>ctrl</sub>	In - Out 1, 2		1	8	μΑ

Note) \*: Designed specification

GN04054N Panasonic

#### ■ Test Circuit



## ■ Logic Table

ON Course	V <sub>ctrl1</sub>	V <sub>ctrl2</sub>
In - Out 1	Н	L
In - Out 2	L	Н

2 SGB00022AED

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## ■ This product contains Gallium Arsenide (GaAs).

GaAs powder and vapor are hazardous to human health if inhaled or ingested. Do not burn, destroy, cut, cleave off, or chemically dissolve the product. Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.

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